

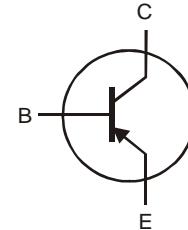


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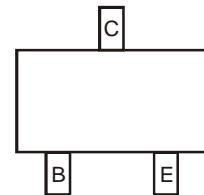
## DSS5320T PNP SURFACE MOUNT TRANSISTOR

### Features

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- “Lead Free”, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)



Marking ZP4



SOT-23

Notes:

1. No purposefully added lead.
2. Diodes Inc's "Green" Policy can be found on our



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### Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	-20	V
Collector-Emitter Voltage	$V_{CEO}$	-20	V
Emitter-Base Voltage	$V_{EBO}$	-5	V
Peak Pulse Current	$I_{CM}$	-5	A
Repetitive Peak Pulse Current (Note 4)	$I_{CRP}$	-3	A
Continuous Collector Current	$I_C$	-2	A
Base Current	$I_B$	-0.5	A

### Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) @ $T_A = 25^\circ\text{C}$	$P_D$	600	mW
Thermal Resistance, Junction to Ambient Air (Note 4) @ $T_A = 25^\circ\text{C}$	$R_{\theta JA}$	209	°C/W
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	°C

Notes: 4. Operated under pulsed conditions: pulse width  $\leq 100\text{ms}$ , duty cycle  $\leq 0.25$ .

5. Device mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

### Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Collector-Base Cutoff Current	$I_{CBO}$	—	—	-100	nA	$V_{CB} = -20\text{V}, I_E = 0$
		—	—	-50	$\mu\text{A}$	$V_{CB} = -20\text{V}, I_E = 0, T_A = 150^\circ\text{C}$
Emitter-Base Cutoff Current	$I_{EBO}$	—	—	-100	nA	$V_{EB} = -5\text{V}, I_C = 0$
Collector-Base Breakdown Voltage	$BV_{CBO}$	-20	—	—	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 6)	$BV_{CEO}$	-20	—	—	V	$I_C = -10\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-5	—	—	V	$I_E = -100\mu\text{A}$
DC Current Gain (Note 5)	$h_{FE}$	220	—	—	—	$V_{CE} = -2\text{V}, I_C = -0.1\text{A}$
		220	—	—		$V_{CE} = -2\text{V}, I_C = -0.5\text{A}$
		200	—	—		$V_{CE} = -2\text{V}, I_C = -1\text{A}$
		150	—	—		$V_{CE} = -2\text{V}, I_C = -2\text{A}$
		100	—	—		$V_{CE} = -2\text{V}, I_C = -3\text{A}$
Collector-Emitter Saturation Voltage (Note 6)	$V_{CE(sat)}$	—	—	-70	mV	$I_C = -0.5\text{A}, I_B = -50\text{mA}$
		—	—	-130		$I_C = -1\text{A}, I_B = -50\text{mA}$
		—	—	-230		$I_C = -2\text{A}, I_B = -100\text{mA}$
		—	—	-210		$I_C = -2\text{A}, I_B = -200\text{mA}$
		—	—	-300		$I_C = -3\text{A}, I_B = -300\text{mA}$
Equivalent On-Resistance	$R_{CE(sat)}$	—	—	105	$\text{m}\Omega$	$I_E = -2\text{A}, I_B = -200\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	—	-1.1	V	$I_C = -2\text{A}, I_B = -100\text{mA}$
		—	—	-1.2	V	$I_C = -3\text{A}, I_B = -300\text{mA}$
Base-Emitter Turn-on Voltage	$V_{BE(on)}$	—	—	-1.2	V	$V_{CE} = -2\text{V}, I_C = -1\text{A}$
Transition Frequency	$f_T$	100	180	—	MHz	$V_{CE} = -5\text{V}, I_C = -100\text{mA}, f = 100\text{MHz}$
Output Capacitance	$C_{ob}$	—	25	50	pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}$
Turn-On Time	$t_{on}$	—	67	—	ns	$V_{CC} = -10\text{V}, I_C = -1\text{A}, I_{B1} = -I_{B2} = -50\text{mA}$
Delay Time	$t_d$	—	23	—	ns	
Rise Time	$t_r$	—	44	—	ns	
Turn-Off Time	$t_{off}$	—	224	—	ns	
Storage Time	$t_s$	—	184	—	ns	
Fall Time	$t_f$	—	40	—	ns	

Notes: 6. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.



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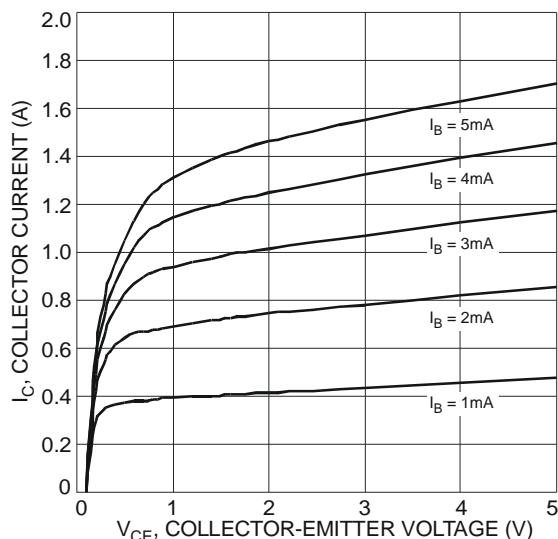


Fig. 3 Typical Collector Current vs. Collector-Emitter Voltage

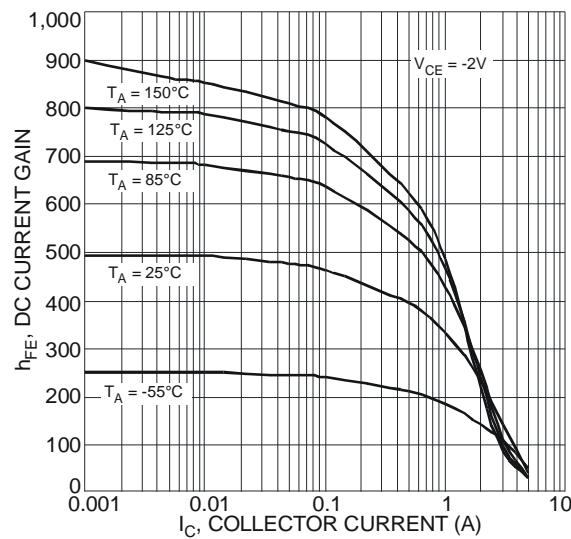


Fig. 4 Typical DC Current Gain vs. Collector Current

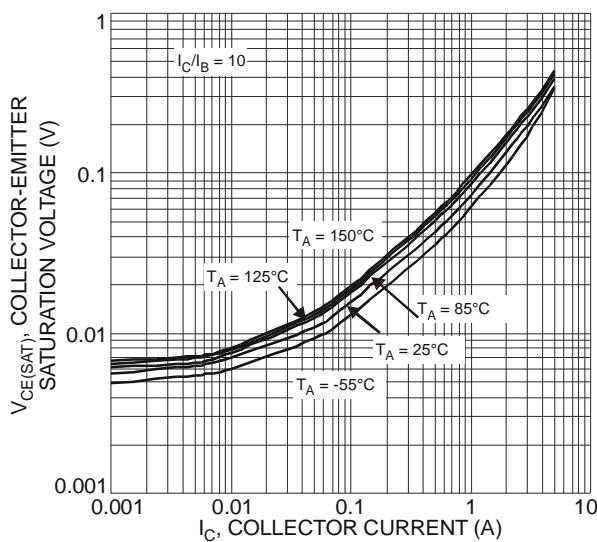


Fig. 5 Typical Collector-Emitter Saturation Voltage vs. Collector Current

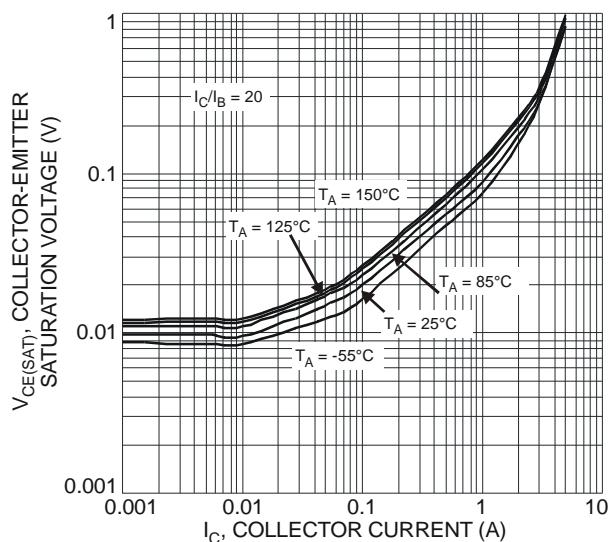


Fig. 6 Typical Collector-Emitter Saturation Voltage vs. Collector Current

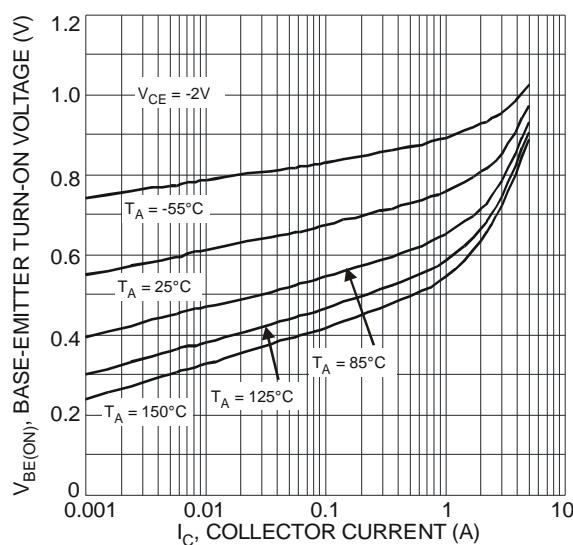


Fig. 7 Typical Base-Emitter Turn-On Voltage vs. Collector Current

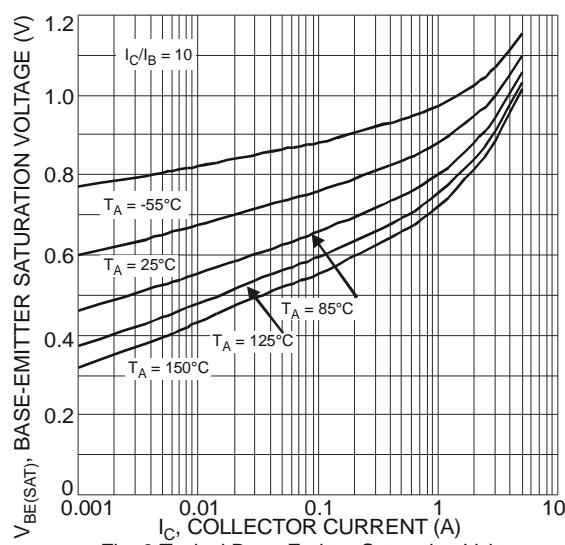


Fig. 8 Typical Base-Emitter Saturation Voltage vs. Collector Current

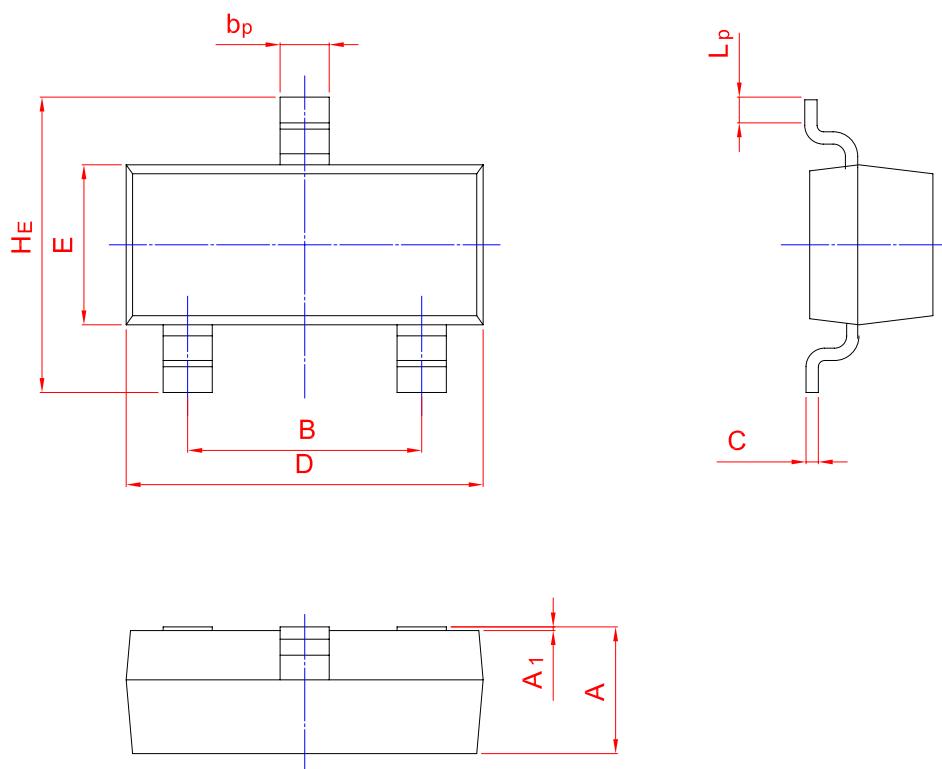


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## PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

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UNIT	A	B	$b_p$	C	D	E	$H_E$	$A_1$	$L_p$
mm	1.40 0.95	2.04 1.78	0.50 0.35	0.19 0.08	3.10 2.70	1.65 1.20	3.00 2.20	0.100 0.013	0.50 0.20